HD31756
SOLID STATE HIGH POWER AMPLIFIER

Communications Corp.

FEATURES

Class AB linear GaN design
Instantaneous ultra-wide bandwidth
Suitable for all single channel modulations standards
Built-in protection circuits
High reliability and ruggedness



ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	1.0 - 6.0 GHz	
Power Output Psat	2 Watt Typ	CW
Power Gain	33 dB Min	
Gain Flatness	4.0 dB p-p Max	
Input Return Loss	10 dB Min	Relative to 50 Ohm
Harmonics 2^{nd} / 3rd	>15 dBc / >20 dBc Typ	At rated Pout
2-Tone Intermodulation (IMD)	>30 dBc Typ	23dBm/Tone, Δ = 1MHz
Non Harmonics Spurious	>60 dBc	
Operating Voltage	28 VDC Nom	
Current Consumption	0.8 Amp Max	At rated Pout
Max Input Power Protection	+8 dBm	10 Sec without damage
Load VSWR Protection	∞ : 1	At rated Pout for 1 minute

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Case Temperature	-20 to +75 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non Condensation

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions	125 x 63 x 27 mm	
Weight	400 gr.	Typical Weight
RF Connectors In/Out	SMA female	
DC Power / Interface Connector	9-Pin D-Sub	
Cooling	External Heatsink	Forced air required

D-SUB CONNECTOR PIN ASSIGNMENT

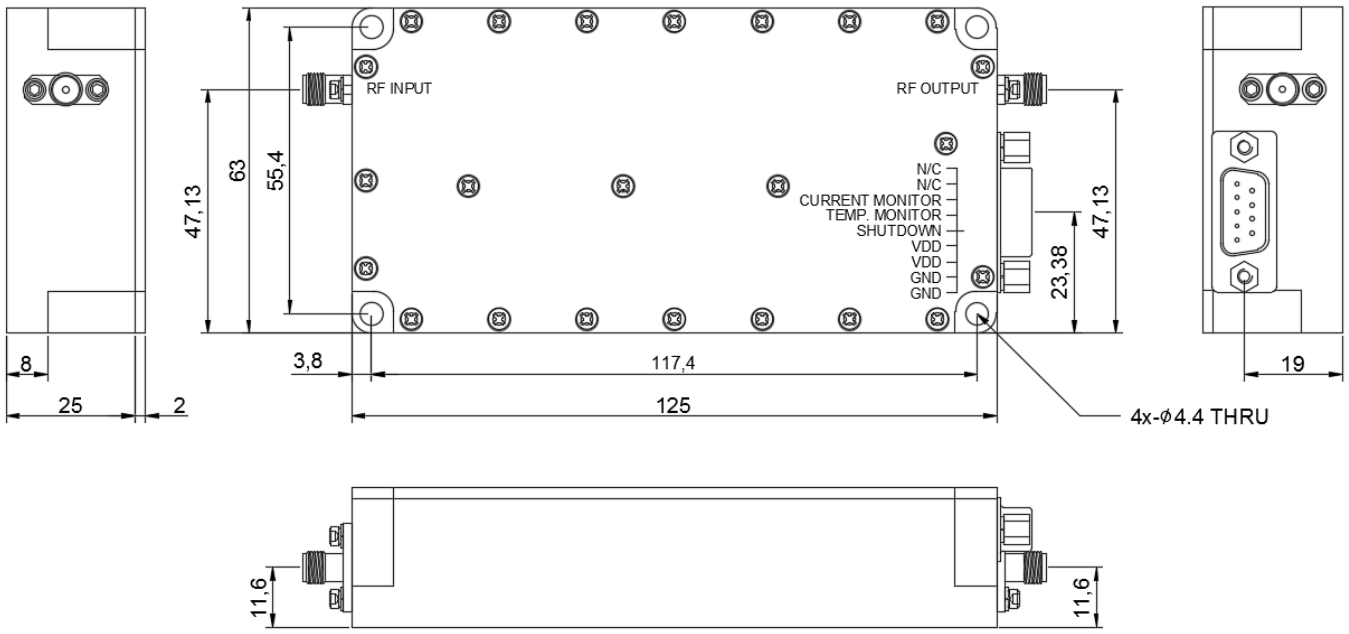
Pin	Function	Description
1	FWD	N/C
2	REV	N/C
3	CURRENT SENSOR	I_D@20mV/100mA Typ
4	TEMP SENSOR	V_T@10mV/°C + 500mV Typ
5	SHUTDOWN	TTL
6, 7	VDD	28VDC
8, 9	GND	Ground

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OUTLINE DRAWING



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